

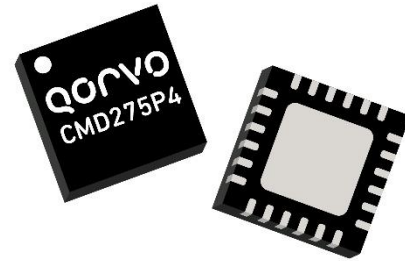


# THE DATASHEET OF CMD275P4

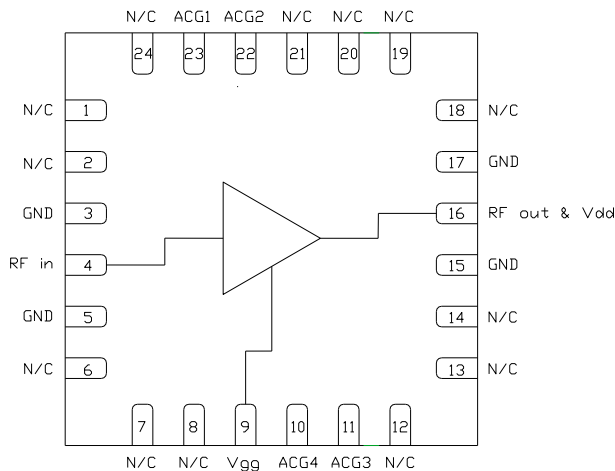


### Product Overview

The CMD275P4 is a wideband GaAs MMIC low phase noise amplifier housed in a leadless surface mount package that is ideally suited for military, space and communications systems. At 10 GHz the device delivers 16 dB of gain, a saturated output power of +20.5 dBm and a noise figure of 5.5 dB. Also with an input signal of 10 GHz the amplifier provides low phase noise performance of -165 dBc/Hz at 10 kHz offset. The CMD275P4 is a 50 ohm matched design which eliminates the need for RF port matching.



### Functional Block Diagram



### Key Features

- Ultra-Wideband Performance
- Low Phase Noise
- Low Current Consumption
- Pb-Free RoHs Compliant 4x4 QFN Package

### Ordering Information

Part No.	Description
CMD275P4	DC-26.5 GHz Low Phase Noise Amplifier, 100 Piece 7" Reel
CMD275P4-EVB	Evaluation Board

### Electrical Performance ( $V_{dd} = 5.0\text{ V}$ , $V_{gg} = 3.0\text{ V}$ , $T_A = 25\text{ }^\circ\text{C}$ , $F = 10\text{ GHz}$ )

Parameter	Min	Typ	Max	Units
Frequency Range		DC - 26.5		GHz
Gain		16		dB
Input Return Loss		18		dB
Output Return Loss		20		dB
Noise Figure		5.5		dB
Output P1dB		18		dBm
Saturated Output Power		20.5		dBm
Phase Noise @ 10 kHz Offset		-165		dBc/Hz
Supply Current		74		mA

## Absolute Maximum Ratings

Parameter	Rating
Drain Voltage, $V_{dd}$	7.5 V
Gate Voltage, $V_{gg}$	3.5 V
RF Input Power	+15 dBm
Channel Temperature, $T_{ch}$	150 °C
Power Dissipation, $P_{diss}$	510 mW
Thermal Resistance, $\theta_{JC}$	127.5 °C/W
Operating Temperature	-40 to 85 °C
Storage Temperature	-55 to 150 °C

Exceeding any one or combination of the maximum ratings may cause permanent damage to the device.

## Recommended Operating Conditions

Parameter	Min	Typ	Max	Units
$V_{dd}$	4.0	5.0	7.0	V
$I_{dd}$		74		mA
$V_{gg}$	0	3.0	3.3	V
$I_{gg}$		3.7		mA

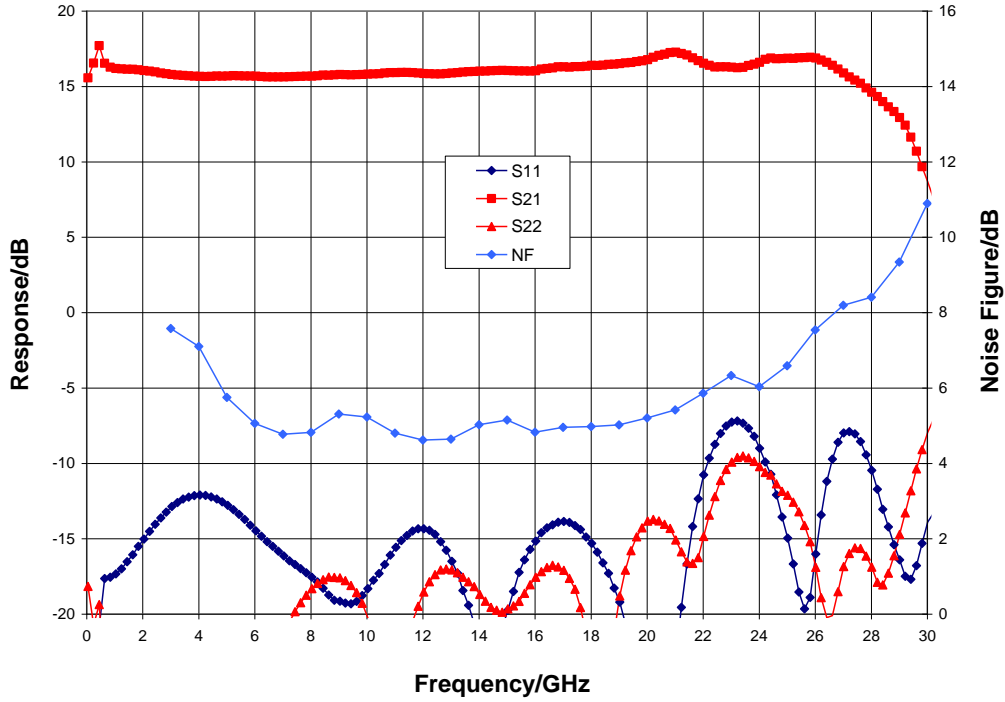
Electrical performance is measured at specific test conditions. Electrical specifications are not guaranteed over all recommended operating conditions.

## Electrical Specifications ( $V_{dd} = 5.0$ V, $V_{gg} = 3.0$ V, $T_A = 25$ °C)

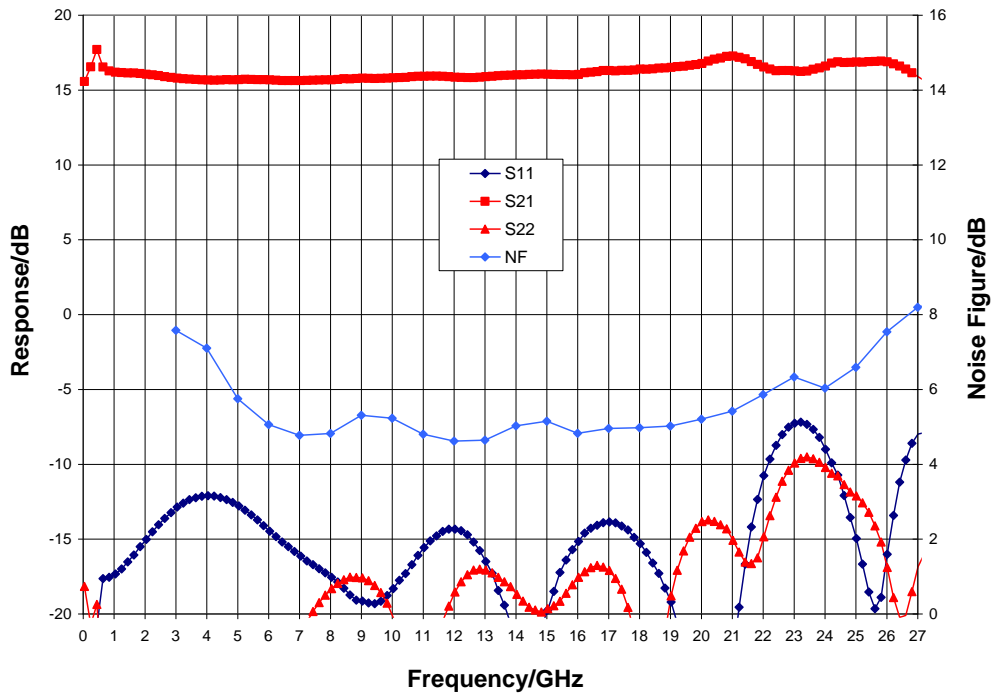
Parameter	Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	Units
Frequency Range	DC - 10			10 - 20			20 - 26			GHz
Gain	13	15.5		13	16		13.5	16.5		dB
Noise Figure		6			5			6		dB
Input Return Loss		13			15			10		dB
Output Return Loss		18			18			13		dB
Output P1dB	15.5	18.5		13	17		11	15		dBm
Saturated Output Power		21			19			17.5		dBm
Output IP3		29			28.5			25		dBm
Phase Noise @ 10 kHz Offset		-165			-165			-165		dBc/Hz
Supply Current	52	74	110	52	74	110	52	74	110	mA

Typical Performance

Broadband Performance,  $V_{dd} = 5.0\text{ V}$ ,  $V_{gg} = 3.0\text{ V}$ ,  $I_{dd} = 74\text{ mA}$ ,  $T_A = 25\text{ }^\circ\text{C}$

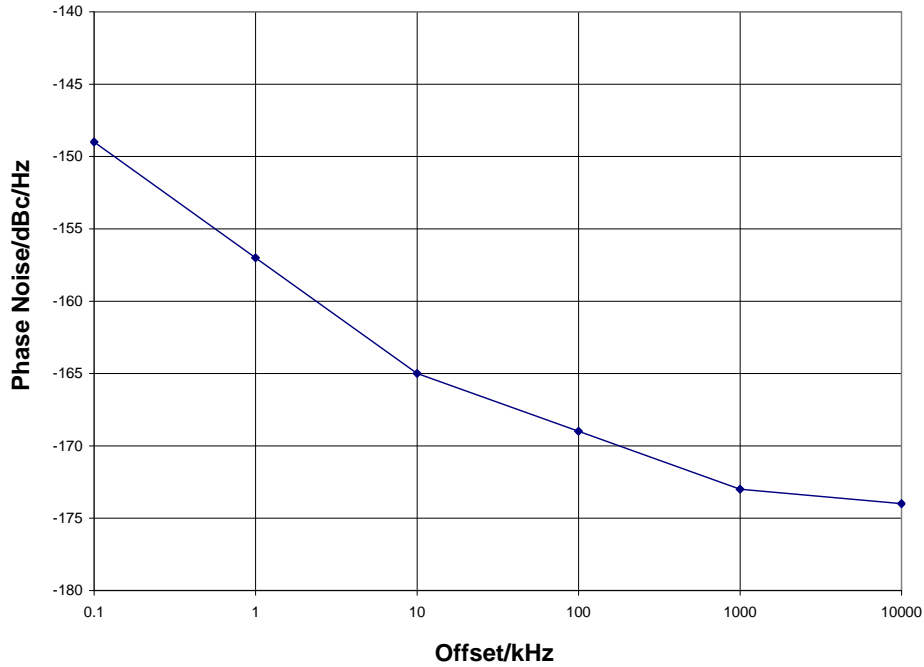


Narrow-band Performance,  $V_{dd} = 5.0\text{ V}$ ,  $V_{gg} = 3.0\text{ V}$ ,  $I_{dd} = 74\text{ mA}$ ,  $T_A = 25\text{ }^\circ\text{C}$

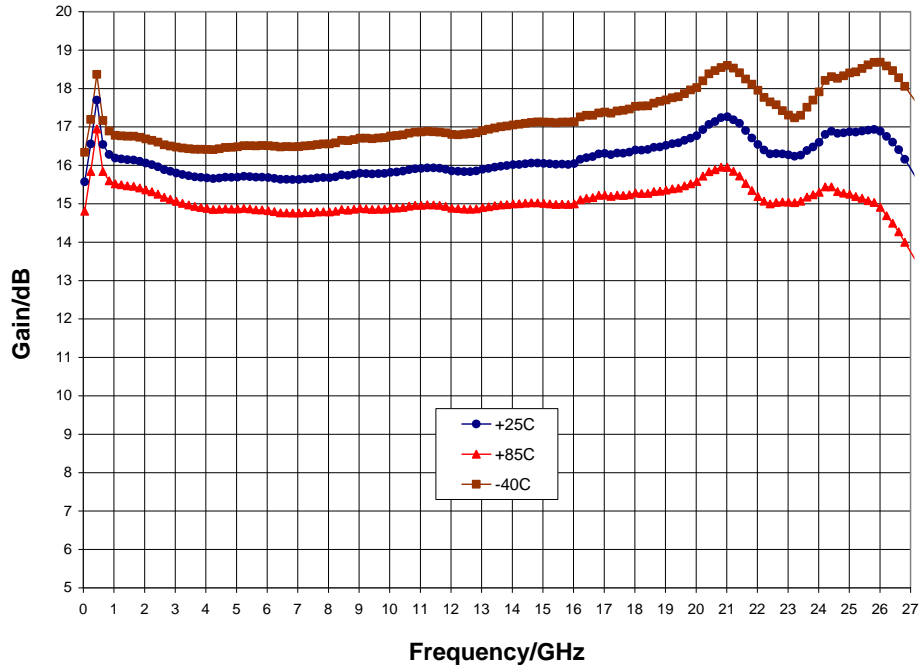


Typical Performance

Additive Phase Noise @ Psat, V<sub>dd</sub> = 5.0 V, V<sub>gg</sub> = 3.0 V, T<sub>A</sub> = 25 °C

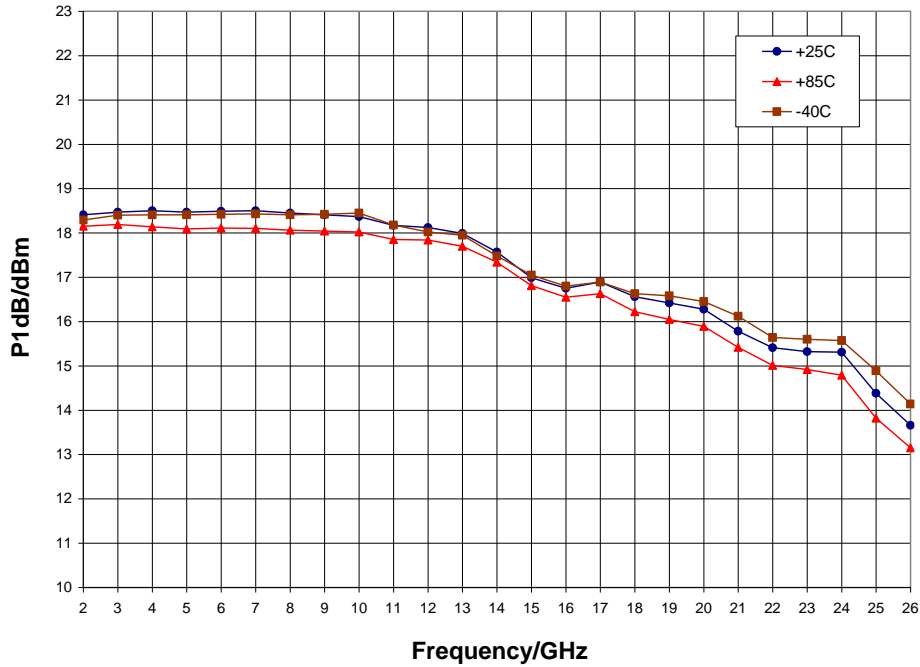


Gain vs. Temperature, V<sub>dd</sub> = 5.0 V, V<sub>gg</sub> = 3.0 V

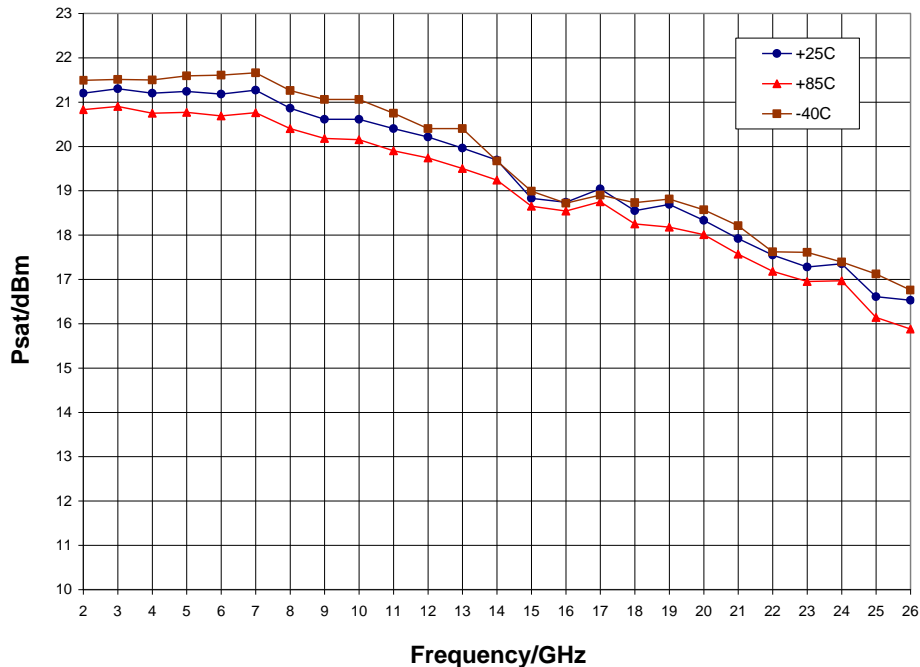


Typical Performance

P1dB vs. Temperature,  $V_{dd} = 5.0\text{ V}$ ,  $V_{gg} = 3.0\text{ V}$

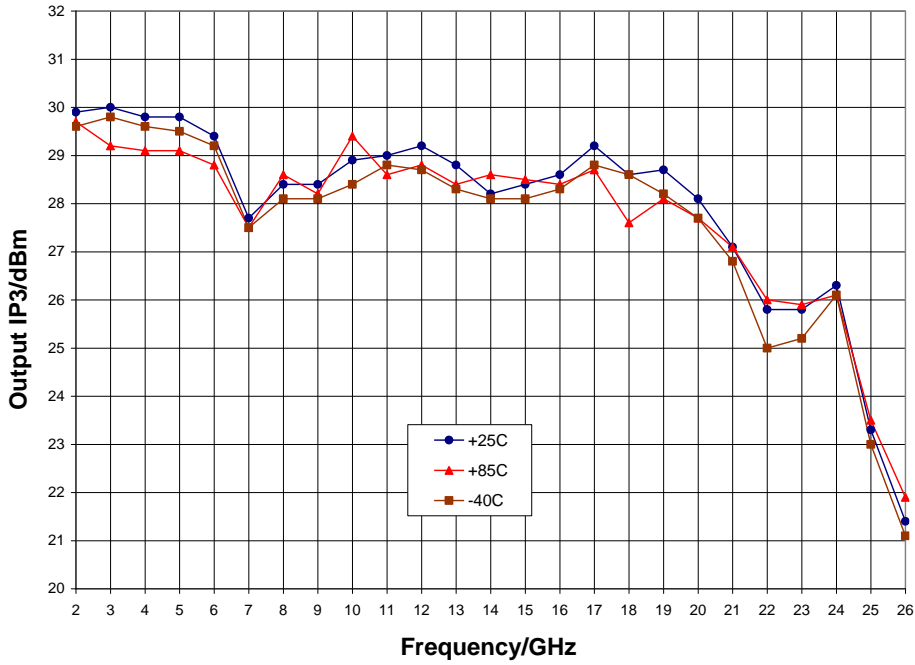


Psat vs. Temperature,  $V_{dd} = 5.0\text{ V}$ ,  $V_{gg} = 3.0\text{ V}$

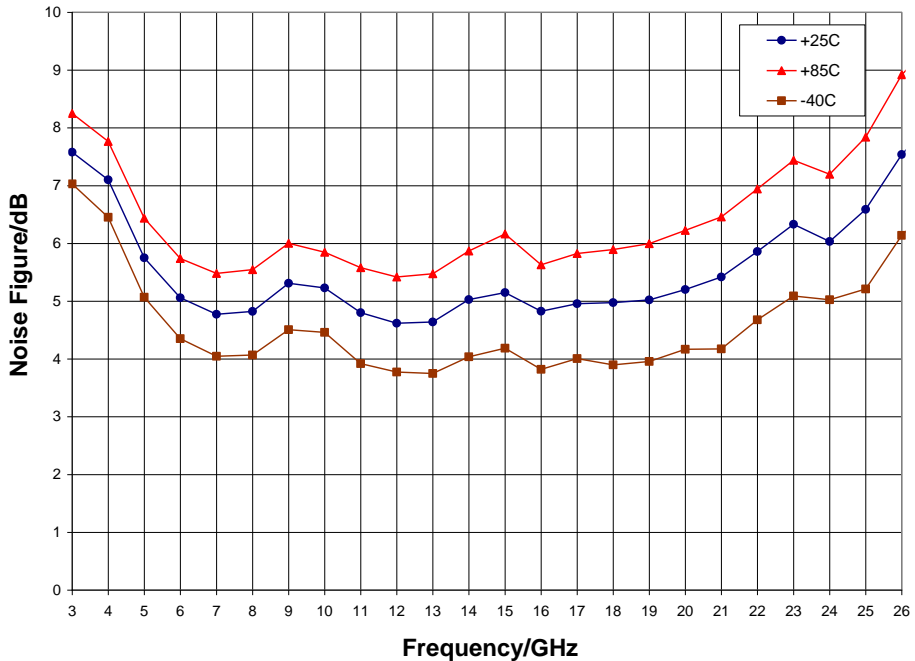


Typical Performance

Output IP3 vs. Temperature,  $V_{dd} = 5.0\text{ V}$ ,  $V_{gg} = 3.0\text{ V}$

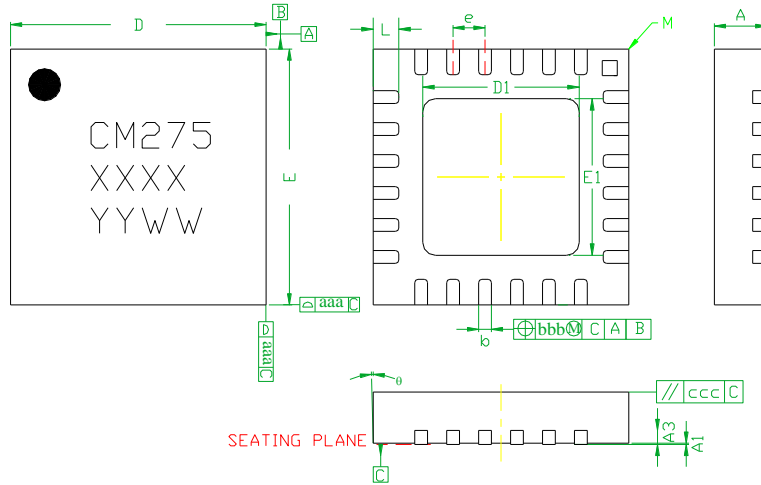


Noise Figure vs. Temperature,  $V_{dd} = 5.0\text{ V}$ ,  $V_{gg} = 3.0\text{ V}$



## Mechanical Information

### Package Information and Dimensions



SYMBOLS	DIMENSIONS IN MILLIMETERS		
	MIN	NOM	MAX
A	0.80	0.90	1.00
A1	0	0.02	0.05
A3	---	0.25REF.	---
b	0.18	0.23	0.30
D	3.85	4.00	4.15
D1	2.40	2.50	2.60
E	3.85	4.00	4.15
E1	2.40	2.50	2.60
e	---	0.50BSC	---
L	0.30	0.40	0.50
ø	0	---	12
aaa	---	0.25	---
bbb	---	0.10	---
ccc	---	0.10	---
M	---	---	0.05

**Notes:**

1. Dimensions are in millimeters
2. RoHs compliant mold compound
3. Lead frame material: Copper alloy
4. Lead finish: 100% matte Sn
5. Indicated dimension/tolerance applies to leads and exposed pads

### Recommended PCB Land Pattern

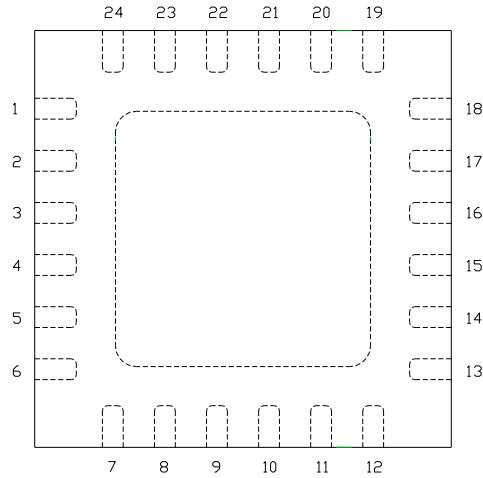
Qorvo recommends that the user develop the land pattern that will provide the best design for proper solder reflow and device attach for their specific application. Please review Qorvo Application Note AN 105 for a recommended land pattern approach.

### Recommended Solder Reflow Profile

Qorvo recommends screen printing with belt furnace reflow to ensure proper solder reflow and device attach. Please review Qorvo Application Note AN 102 for a recommended solder reflow profile.

## Pin Description

### Pin Diagram

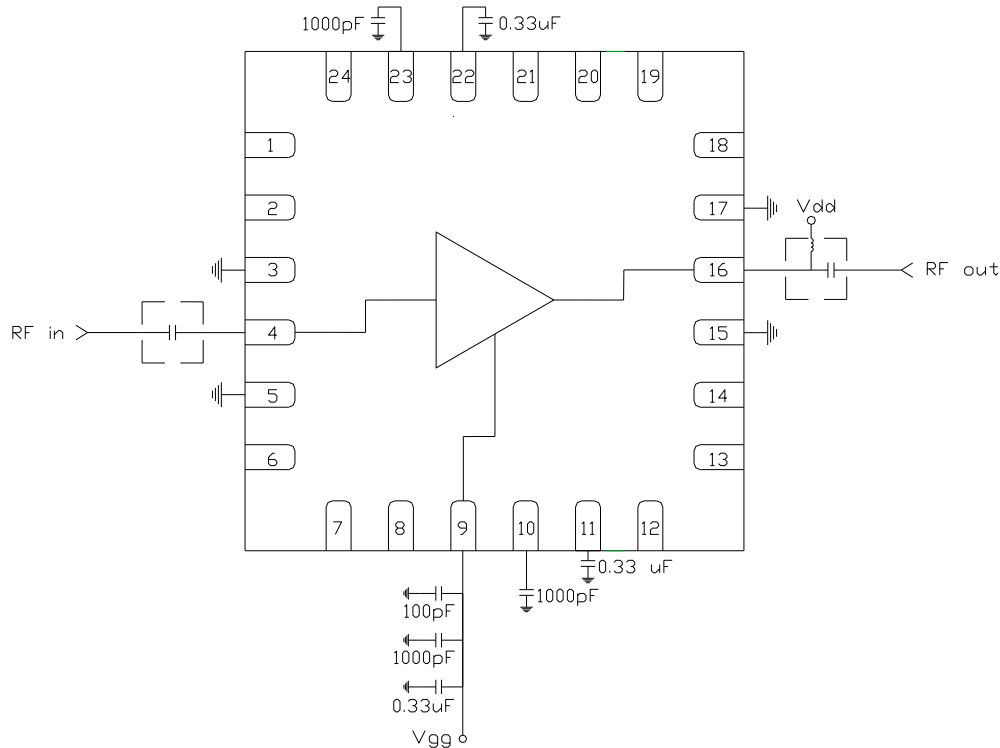


### Functional Description

Pin	Function	Description	Schematic
1, 2, 6 - 8, 12 - 14, 18 - 21, 24	N/C	No connection required These pins may be connected to RF / DC ground	
4	RF in	50 ohm matched input	
22, 23	ACG2, 1	Low frequency termination Attach bypass capacitors per application circuit	
16	RF out & V <sub>dd</sub>	Power supply voltage and 50 ohm matched output	
10, 11	ACG4, 3	Low frequency termination Attach bypass capacitors per application circuit	
9	V <sub>gg</sub>	Power supply voltage Decoupling and bypass caps required	
3, 5, 15, 17 and die paddle	Ground	Connect to RF / DC ground	

## Applications Information

### Application Circuit



### Biasing and Operation

The CMD275P4 is biased with a positive drain supply and positive gate supply. Performance is optimized when the drain voltage is set to +5.0 V. The recommended gate voltage is +3.0 V. The preferred biasing procedure is as follows:

Turn ON procedure:

1. Apply drain voltage  $V_{dd}$  and set to +5 V
2. Apply gate voltage  $V_{gg}$  and set to +3 V

Turn OFF procedure:

1. Turn off gate voltage  $V_{gg}$
2. Turn off drain voltage  $V_{dd}$

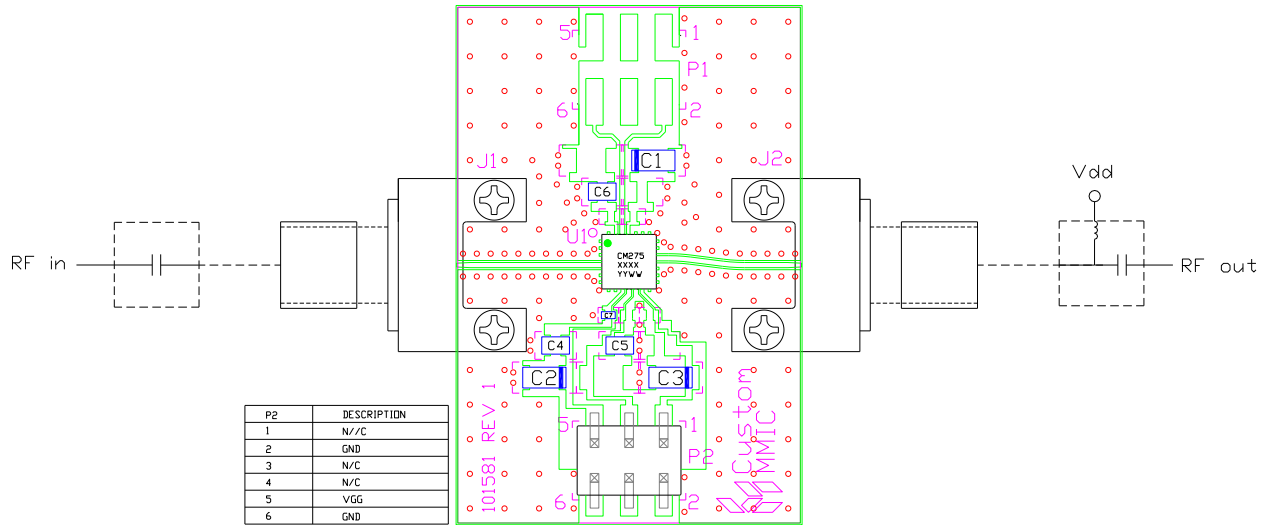
The preferred biasing procedure has been proven to be robust, and should be used whenever possible. However, the CMD275P4 does allow for simultaneous biasing (applying  $V_{dd}$  and  $V_{gg}$  at the same time), and the use of single voltage supply.

Refer to Application Note 103: Amplifier Biasing Techniques for instructions on how to implement a single supply biasing scheme.

For either approach, RF power can be applied at any time.

## Applications Information

### Evaluation Board



### Bill of Material

Designator	Value	Description
J1, J2		SMA End Launch Connector
P2		6 Pin DC Header
C1 - C3	0.33 $\mu$ F	Capacitor, Tantalum
C4 - C6	1000 pF	Capacitor, 0603
C7	100 pF	Capacitor, 0402
U1		CMD275P4 Driver Amplifier
PCB		101581 Evaluation PCB

**GaAs MMIC devices are susceptible to damage from Electrostatic Discharge. Proper precautions should be observed during handling, assembly and test.**

## Handling Precautions

Parameter	Rating	Standard
ESD – Human Body Model (HBM)	Class 1A	ESDA / JEDEC JS-001-2012
MSL – Moisture Sensitivity Level	Level 1	JEDEC standard IPC/JEDEC J-STD-020



Caution!  
ESD-Sensitive Device

## RoHS Compliance

This part is compliant with 2011/65/EU RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment) as amended by Directive 2015/863/EU.

This product also has the following attributes:

- Lead Free
- Antimony Free
- TBBP-A (C<sub>15</sub>H<sub>12</sub>Br<sub>4</sub>O<sub>2</sub>) Free
- SVHC Free
- Halogen Free
- PFOS Free

## Contact Information

For the latest specifications, additional product information, worldwide sales and distribution locations:

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